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Rohm Semiconductor RSD220N06TL

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简体中文 繁體中文 한국어 日本語 ROHIT RSD220N06 Text Size A A Site Search Search 0 Site Map HOME. Products > Discrete Semiconductors > Transistors > MOSFETs > RSD220N06 ICs Transistors Inquiries concerning our products **4V Drive Nch MOSFET** 2010.07.21 Discrete RSD220N06 Semiconductors The industry's highest efficiency MOSFETs for Transistors DC/DC power supplies: ECOMOSTM Data Sheet Design Model SPICE ア MOSFETs Bipolar Transistors 2010.02.25 **Reliability information Operation notes Condition of soldering** ROHM's ultra-low Digital Transistors voltage drive MOSFETs - ECOMOSTM - enable Print out Complex Transistors driving from a control Diodes Outline voltage of 0.9V [Product description] Power MOSFETs are made as low ON-resistance devices by the micro-2010.01.22 **Opto Electronics** processing technologies useful for wide range of applications.Broad lineup ROHM continues to offer its lineup of ultra-low covering compact types, high-power types and complex types to meet various Passive Components voltage MOSFETs ECOMOS™ series needs in the market. Modules (Sub Systems) 2009.05.29 Features Energy Saving High speed trr High **ECO** Devices Voltage Resistance PrestoMOSTM Series E4V-drive type Nch Power MOSFET Product Information CPT3 **Product specifications** 2009.02.27 Dimensions ROHM's new RC series of 250V MOSFETs Absolute maximum ratings (Ta=25°C) CPT3 (SC-63) (SCE42) Eollector | By Rated parameters Standard value Conditions Drain-Source voltage V_{DSS}(V) 8.5 DHit 60 2.9 Precautions for Gate-Source voltage V_{GSS}(V) 20 driving TRs safety Drain current(continuous) I_D(A) ±22 3 100 Knowledge required Source current(body Di) I_S(A) 16 ю, for the die temp. 0.16 (10 2.9 (10 (20 125 1 Total power dissipation P_D(W) 20 calculation Click to enlarge. Channel temperature Tch(°C) 150 What is a transistor? Storage temperature Tstg(°C) -55 to +150 Equivalent circuit diagram G Gate D Dsain Operation notes Pant No. explanation Package Ġ Ē ŝ 1 ESO PROTECTION DIODE 2 BODY DIODE Taping specifications Soldering conditions >Surface mounted type transistors >Leaded type transistors *The contents described here are just outline for introduction. Please obtain the specification sheets from us for thorough check before use Status Product Storage conditions Status Packing Package Samples RoHS Part No. Package Sales style quantity Explanation of symbols CPT3/SC-63/SOT-428 @ROHM/JEDEC/JEITA RSD220N06TL Active Yes 2500 Inquiry taping FAQ *1 Active: Production or current type Preparation: Preliminary type Preview: Development type ROHM Internet Direct *2 Display ranks are representative hFE rank.Please understand that selection of hFE rank is not possible RoHS directive compliance Others Contact us Please check the details on "Product List" for Others. Top of Page Privacy Policy Terms & Conditions Copyright © 1997-2010 ROHM Co., Ltd